

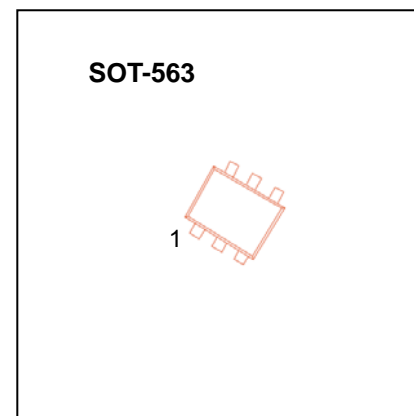
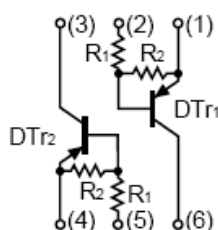
dual digital transistors (PNP+PNP)

FEATURES

- Two DTA114Y chips in a package
- Mounting possible with SOT-563 automatic mounting machines
- Transistor elements are independent, eliminating interference
- Mounting cost and area be cut in half

Marking: B9

Equivalent circuit



Absolute maximum ratings ($T_a=25^\circ\text{C}$)

Symbol	Parameter	Value	Units
V_{CC}	Supply Voltage	-50	V
$I_{C(MAX)}$	Output Current	-100	mA
V_i	Input Voltage	-40 to +6	V
P_D	Power Dissipation	150	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^\circ\text{C}$

Electrical Characteristics ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Input turn-on voltage	$V_{i(on)}$	$V_O=-0.3V, I_O=-1mA$	-1.4			V
Input cut-off voltage	$V_{i(off)}$	$V_{CC}=-5V, I_O=-100\mu A$			-0.3	V
Output voltage	$V_{O(on)}$	$I_O=-5mA, I_i=-0.25mA$			-0.3	V
Input cut-off current	I_i	$V_i=-5V$			-0.88	mA
Output cut-off current	$I_{O(off)}$	$V_{CC}=-50V, V_i=0$			-0.5	μA
DC current gain	G_i	$V_O=-5V, I_O=-5mA$	68			
Transition frequency	f_T	$V_O=-10V, I_O=5mA, f=100MHz$		250		MHz
Input resistance	R_1		7		13	K Ω
Resistance ratio	R_2/R_1		3.7		5.7	